

ZXMP4A16G

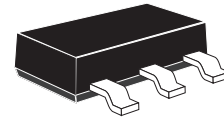
40V P-CHANNEL ENHANCEMENT MODE MOSFET

SUMMARY

$V_{(BR)DSS} = -40V$; $R_{DS(on)} = 0.060\Omega$; $I_D = -6.4A$

DESCRIPTION

This new generation of Trench MOSFETs from Zetex utilizes a unique structure that combines the benefits of low on-resistance with fast switching speed. This makes them ideal for high efficiency, low voltage, power management applications.



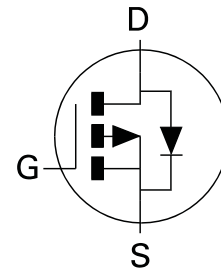
SOT223

FEATURES

- Low on-resistance
- Fast switching speed
- Low threshold
- Low gate drive
- SOT223 package

APPLICATIONS

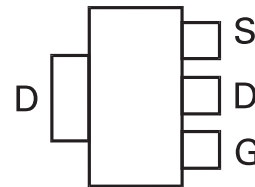
- DC-DC Converters
- Disconnect switches
- Audio output stages
- Motor Control



ORDERING INFORMATION

| DEVICE | REEL SIZE | TAPE WIDTH | QUANTITY PER REEL |
|-------------|-----------|------------|-------------------|
| ZXMP4A16GTA | 7" | 12mm | 1000 units |
| ZXMP4A16GTC | 13" | 12mm | 4000 units |

PINOUT



Top View

DEVICE MARKING

ZXMP
4A16

ZXMP4A16G

ABSOLUTE MAXIMUM RATING

| PARAMETER | SYMBOL | LIMIT | UNIT |
|--|----------------|----------------------|---------------------|
| Drain-Source Voltage | V_{DSS} | -40 | V |
| Gate-Source Voltage | V_{GS} | ± 20 | V |
| Continuous Drain Current ($V_{GS} = -10V$; $T_A = 25^\circ C$) ^(b) ($V_{GS} = -10V$; $T_A = 70^\circ C$) ^(b) ($V_{GS} = -10V$; $T_A = 25^\circ C$) ^(a) | I_D | -6.4 -5.1 -4.6 | A |
| Pulsed Drain Current ^(c) | I_{DM} | -21 | A |
| Continuous Source Current (Body Diode) ^(b) | I_S | -5.2 | A |
| Pulsed Source Current (Body Diode) ^(c) | I_{SM} | -21 | A |
| Power Dissipation at $T_A = 25^\circ C$ ^(a) Linear Derating Factor | P_D | 2.0 16 | W mW/ $^\circ C$ |
| Power Dissipation at $T_A = 25^\circ C$ ^(b) Linear Derating Factor | P_D | 3.9 31 | W mW/ $^\circ C$ |
| Operating and Storage Temperature Range | $T_j; T_{stg}$ | -55 to +150 | $^\circ C$ |

THERMAL RESISTANCE

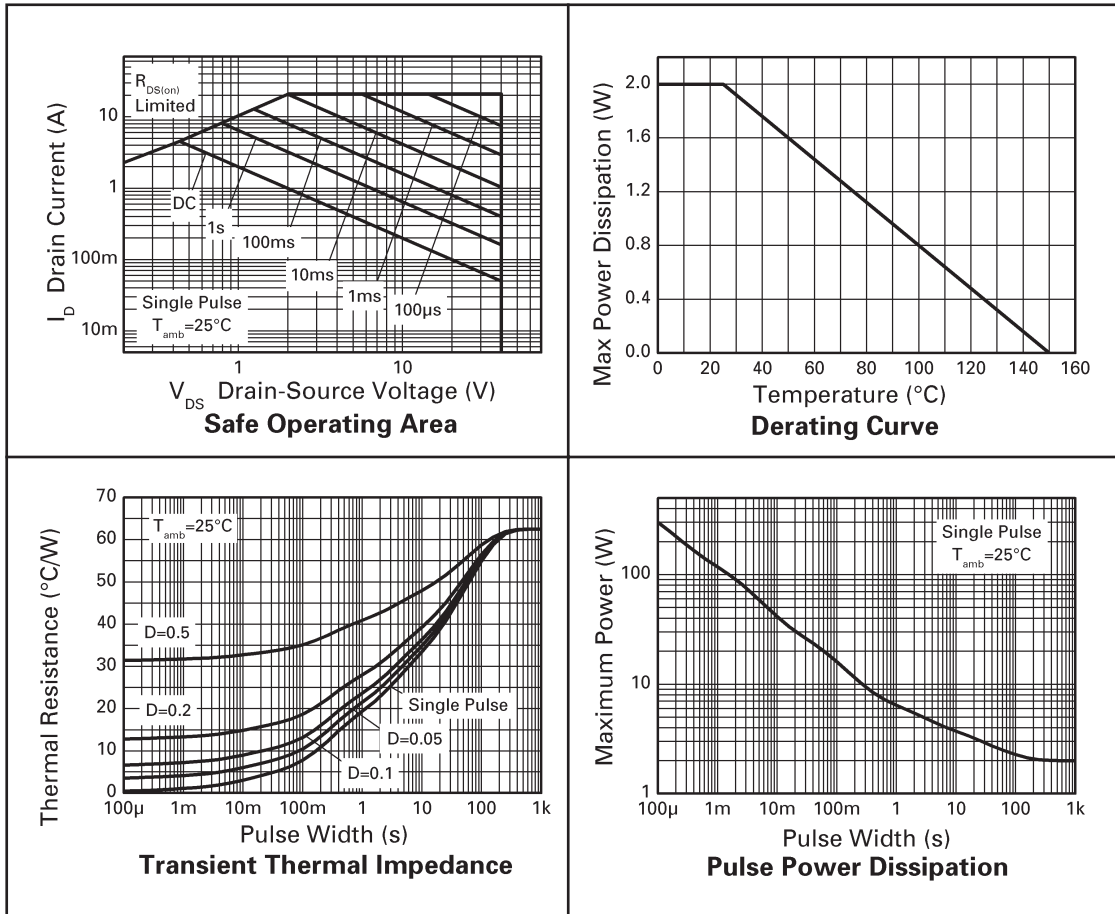
| PARAMETER | SYMBOL | VALUE | UNIT |
|------------------------------------|-----------------|-------|--------------|
| Junction to Ambient ^(a) | $R_{\theta JA}$ | 62.5 | $^\circ C/W$ |
| Junction to Ambient ^(b) | $R_{\theta JA}$ | 32.2 | $^\circ C/W$ |

NOTES

- (a) For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions
- (b) For a device surface mounted on FR4 PCB measured at $t \leq 10$ secs.
- (c) Repetitive rating 25mm x 25mm FR4 PCB, $D=0.05$ pulse width limited by maximum junction temperature.

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CHARACTERISTICS



ZXMP4A16G

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}\text{C}$ unless otherwise stated).

| PARAMETER | SYMBOL | MIN. | TYP. | MAX. | UNIT | CONDITIONS |
|--|---------------|------|-------|----------------|----------------------|---|
| STATIC | | | | | | |
| Drain-Source Breakdown Voltage | $V_{(BR)DSS}$ | -40 | | | V | $I_D = -250\mu\text{A}$, $V_{GS} = 0\text{V}$ |
| Zero Gate Voltage Drain Current | I_{DSS} | | | -1 | μA | $V_{DS} = -40\text{V}$, $V_{GS} = 0\text{V}$ |
| Gate-Body Leakage | I_{GSS} | | | 100 | nA | $V_{GS} = \pm 20\text{V}$, $V_{DS} = 0\text{V}$ |
| Gate-Source Threshold Voltage | $V_{GS(th)}$ | -1.0 | | | V | $I_D = -250\mu\text{A}$, $V_{DS} = V_{GS}$ |
| Static Drain-Source On-State Resistance ⁽¹⁾ | $R_{DS(on)}$ | | | 0.060 0.100 | Ω Ω | $V_{GS} = -10\text{V}$, $I_D = -3.8\text{A}$ $V_{GS} = -4.5\text{V}$, $I_D = -2.9\text{A}$ |
| Forward Transconductance ⁽¹⁾⁽³⁾ | g_{fs} | | 8.85 | | S | $V_{DS} = -15\text{V}$, $I_D = -3.8\text{A}$ |
| DYNAMIC ⁽³⁾ | | | | | | |
| Input Capacitance | C_{iss} | | 1007 | | pF | $V_{DS} = -20\text{V}$, $V_{GS} = 0\text{V}$, $f = 1\text{MHz}$ |
| Output Capacitance | C_{oss} | | 130 | | pF | |
| Reverse Transfer Capacitance | C_{rss} | | 85 | | pF | |
| SWITCHING ⁽²⁾⁽³⁾ | | | | | | |
| Turn-On Delay Time | $t_{d(on)}$ | | 2.33 | | ns | $V_{DD} = -20\text{V}$, $I_D = -1\text{A}$ $R_G \approx 6.0\Omega$, $V_{GS} = -10\text{V}$ |
| Rise Time | t_r | | 8.84 | | ns | |
| Turn-Off Delay Time | $t_{d(off)}$ | | 29.18 | | ns | |
| Fall Time | t_f | | 12.54 | | ns | |
| Gate Charge | Q_g | | 13.6 | | nC | $V_{DS} = -20\text{V}$, $V_{GS} = -5\text{V}$, $I_D = -3.8\text{A}$ |
| Total Gate Charge | Q_g | | 26.1 | | nC | $V_{DS} = -20\text{V}$, $V_{GS} = -10\text{V}$, $I_D = -3.8\text{A}$ |
| Gate-Source Charge | Q_{gs} | | 2.8 | | nC | |
| Gate-Drain Charge | Q_{gd} | | 4.8 | | nC | |
| SOURCE-DRAIN DIODE | | | | | | |
| Diode Forward Voltage ⁽¹⁾ | V_{SD} | | -0.85 | -1.2 | V | $T_J = 25^{\circ}\text{C}$, $I_S = -3.4\text{A}$, $V_{GS} = 0\text{V}$ |
| Reverse Recovery Time ⁽³⁾ | t_{rr} | | 27.2 | | ns | $T_J = 25^{\circ}\text{C}$, $I_F = -3\text{A}$, $di/dt = 100\text{A}/\mu\text{s}$ |
| Reverse Recovery Charge ⁽³⁾ | Q_{rr} | | 25.4 | | nC | |

NOTES

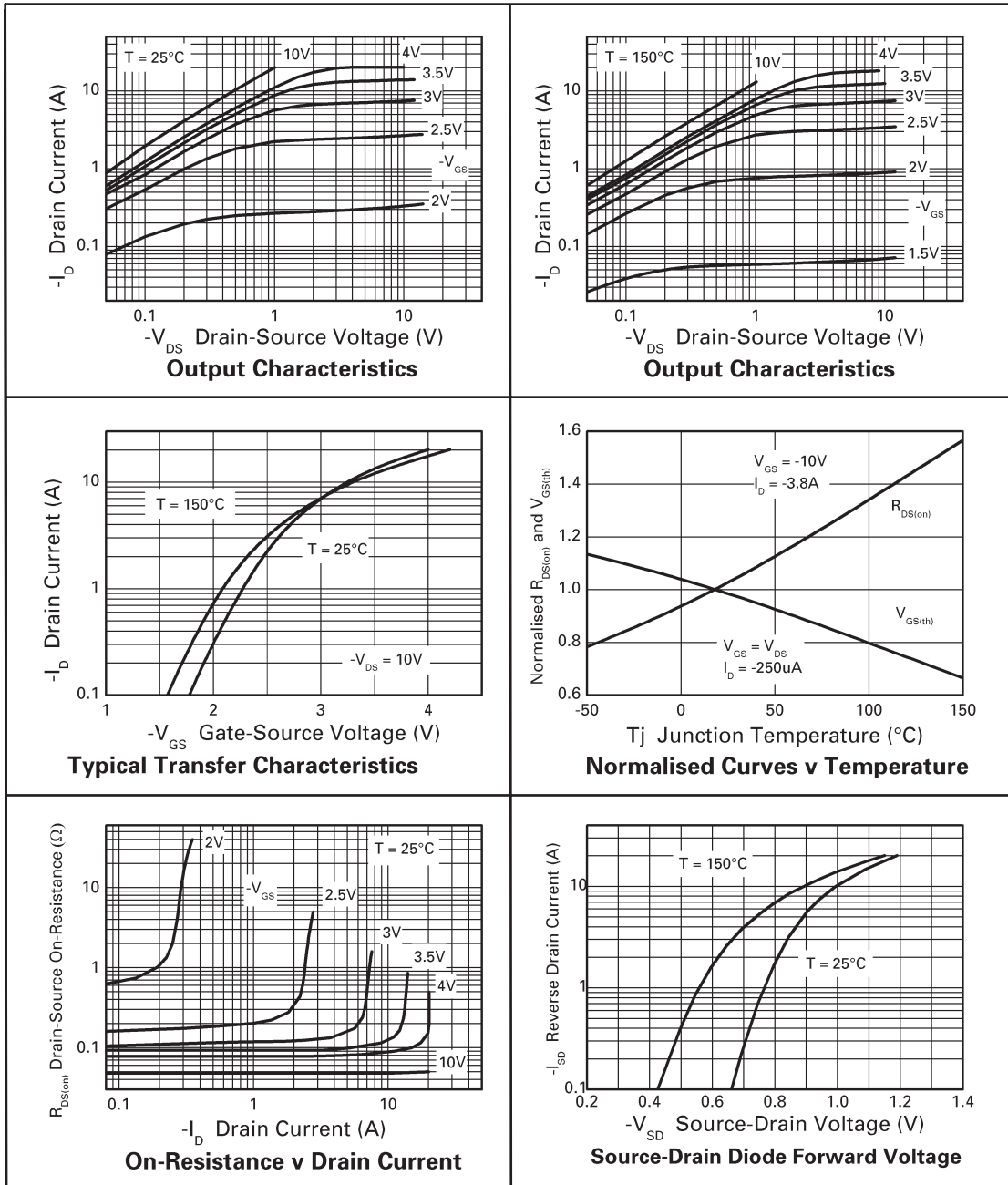
(1) Measured under pulsed conditions. Width $\leq 300\mu\text{s}$. Duty cycle $\leq 2\%$.

(2) Switching characteristics are independent of operating junction temperature.

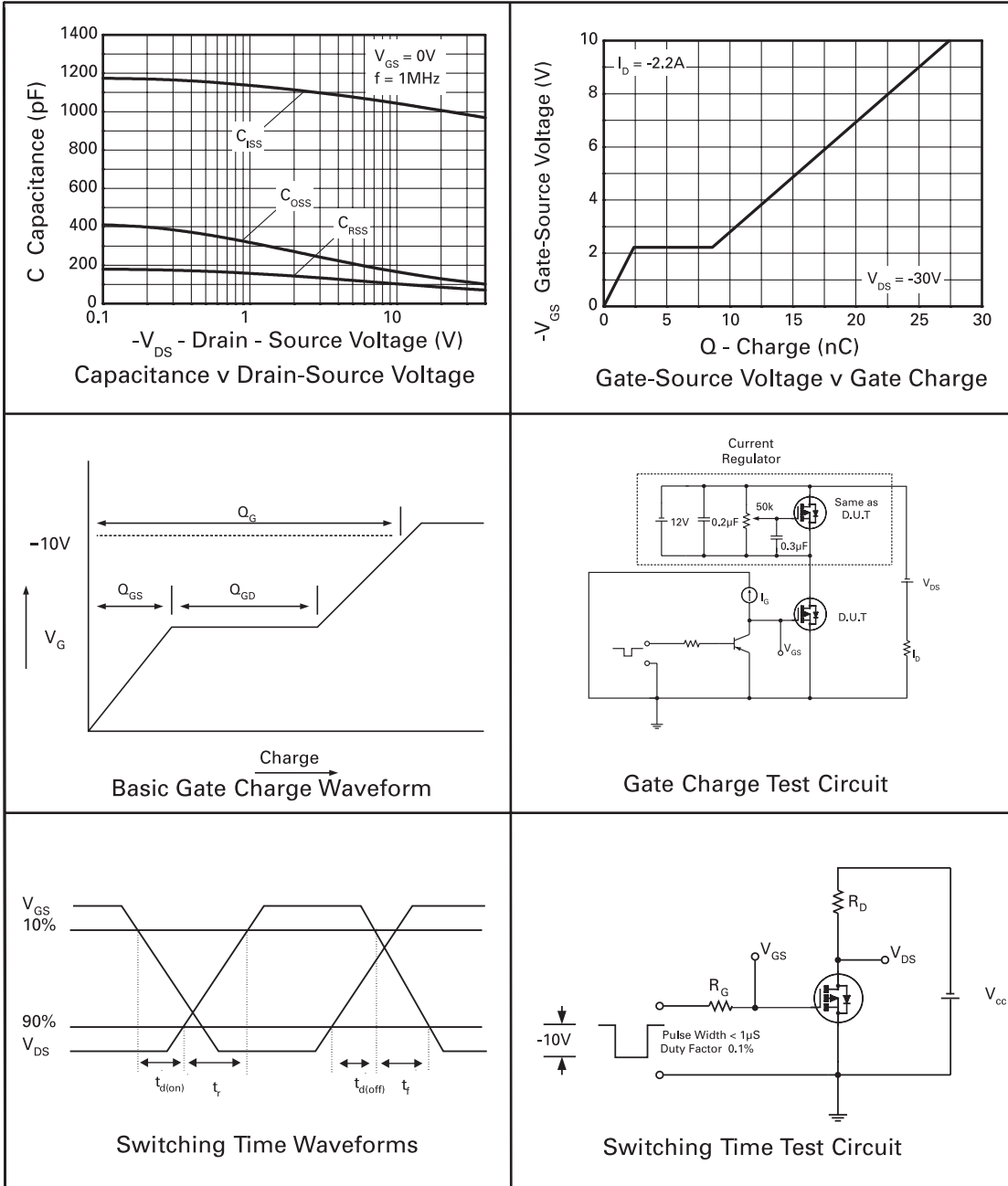
(3) For design aid only, not subject to production testing.

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TYPICAL CHARACTERISTICS

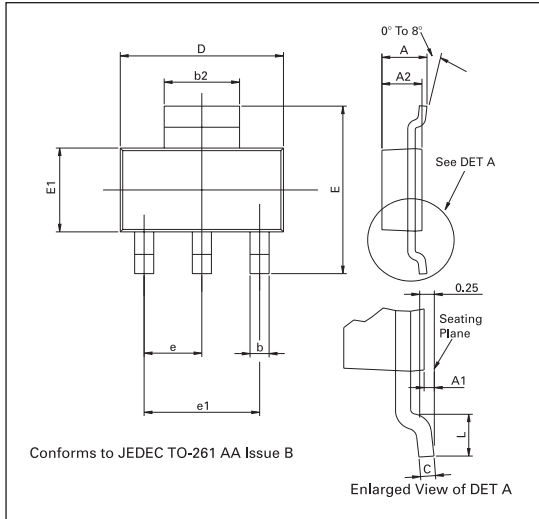


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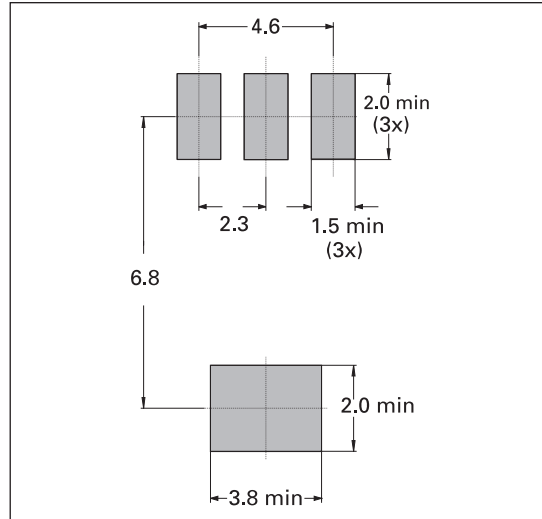


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PACKAGE OUTLINE



PAD LAYOUT DETAILS



PACKAGE DIMENSIONS

| DIM | Millimetres | | Inches | | DIM | Millimetres | | Inches | |
|-----|-------------|------|--------|-------|-----|-------------|------|------------|-------|
| | Min | Max | Min | Max | | Min | Max | Min | Max |
| A | - | 1.80 | - | 0.071 | e | 2.30 BSC | | 0.0905 BSC | |
| A1 | 0.02 | 0.10 | 0.0008 | 0.004 | e1 | 4.60 BSC | | 0.181 BSC | |
| b | 0.66 | 0.84 | 0.026 | 0.033 | E | 6.70 | 7.30 | 0.264 | 0.287 |
| b2 | 2.90 | 3.10 | 0.114 | 0.122 | E1 | 3.30 | 3.70 | 0.130 | 0.146 |
| C | 0.23 | 0.33 | 0.009 | 0.013 | L | 0.90 | - | 0.0355 | - |
| D | 6.30 | 6.70 | 0.248 | 0.264 | | | | | |

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